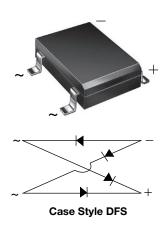
Vishay General Semiconductor

Miniature Glass Passivated Ultrafast Surface-Mount Bridge Rectifiers



LINKS TO ADDITIONAL RESOURCES



| PRIMARY CHARACTERISTICS | | | | | | |
|-------------------------|---------------------------|--|--|--|--|--|
| I _{F(AV)} | 1 A | | | | | |
| V_{RRM} | 50 V, 100 V, 150 V, 200 V | | | | | |
| I _{FSM} | 50 A | | | | | |
| I _R | 5 μΑ | | | | | |
| V_F at $I_F = 1.0 A$ | 1.05 V | | | | | |
| t _{rr} | 50 ns | | | | | |
| T _J max. | 150 °C | | | | | |
| Package | DFS | | | | | |
| Circuit configuration | Quad | | | | | |

FEATURES

- UL recognition, file number E54214
- · Ideal for automated placement
- Glass passivated pellet chip junction
- Ultrafast reverse recovery time for high frequency
- High surge current capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

General purpose use in AC/DC bridge full wave rectification for SMPS, lighting ballaster, adapter, battery charger, home appliances, office equipment, and telecommunication applications.

MECHANICAL DATA

Case: DFS

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked on body

| MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted) | | | | | | |
|--|-----------------------------------|-------------|--------|--------|------------------|------|
| PARAMETER | SYMBOL | EDF1AS | EDF1BS | EDF1CS | EDF1DS | UNIT |
| Maximum repetitive peak reverse voltage | V_{RRM} | 50 | 100 | 150 | 200 | V |
| Maximum RMS voltage | V _{RMS} | 35 | 70 | 106 | 140 | V |
| Maximum DC blocking voltage | V_{DC} | 50 | 100 | 150 | 200 | V |
| Maximum average forward output rectified current at $T_A = 40 ^{\circ}\text{C}^{(1)}$ | I _{F(AV)} | 1.0 | | | | Α |
| Peak forward surge current single half sine-wave superimposed on rated load | I _{FSM} | 50 | | | | Α |
| Rating for fusing (t < 8.3 ms) | I ² t | 10 | | | A ² s | |
| Operating junction and storage temperature range | T _J , T _{STG} | -55 to +150 | | | | °C |

Note

(1) Pulse test: 300 ms pulse width, 1 % duty cycle



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| ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | | | |
|---|---|-----------------|--------|--------|--------|--------|------|
| PARAMETER | TEST CONDITIONS | SYMBOL | EDF1AS | EDF1BS | EDF1CS | EDF1DS | UNIT |
| Maximum instantaneous forward voltage drop per diode | 1.0 A ⁽¹⁾ | V _F | 1.05 | | | | V |
| Maximum DC reverse current at rated DC | T _A = 25 °C | I_ | | 5. | .0 | | μΑ |
| blocking voltage per diode | T _A = 125 °C | IR | 1.0 | | | | mA |
| Maximum reverse recovery time per diode | $I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_{rr} = 0.25 \text{ A}$ | t _{rr} | 50 | | | | ns |

Note

⁽¹⁾ Pulse test: 300 ms pulse width, 1 % duty cycle

| THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | | |
|---|-----------------|--------|--------|--------|--------|--------|
| PARAMETER | SYMBOL | EDF1AS | EDF1BS | EDF1CS | EDF1DS | UNIT |
| Typical thermal resistance (1) | $R_{\theta JA}$ | 38 | | | | °C/W |
| | $R_{\theta JL}$ | | 1: | 2 | |] C/VV |

Note

⁽¹⁾ PCB mounted with 0.2" x 0.2" (5.0 mm x 5.0 mm) copper pad areas

| ORDERING INFORMATION (Example) | | | | | | | |
|--------------------------------|-----------------|------------------------|---------------|----------------------------------|--|--|--|
| PREFERRED P/N | UNIT WEIGHT (g) | PREFERRED PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | | | |
| EDF1DS-E3/45 | 0.406 | 45 | 50 | Tube | | | |
| EDF1DS-E3/77 | 0.406 | 77 | 1500 | 13" diameter paper tape and reel | | | |

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

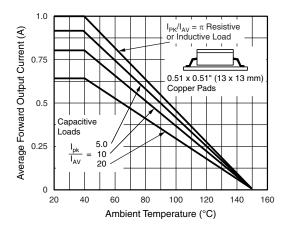


Fig. 1 - Derating Curves Output Rectified Current

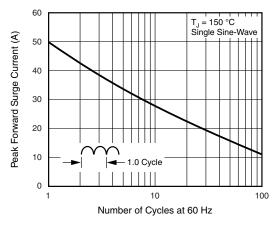


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

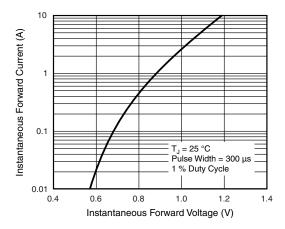


Fig. 3 - Typical Forward Characteristics Per Diode

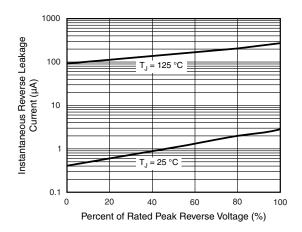


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

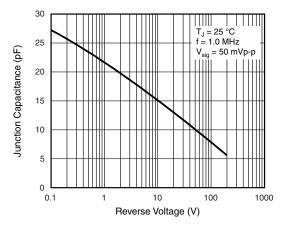
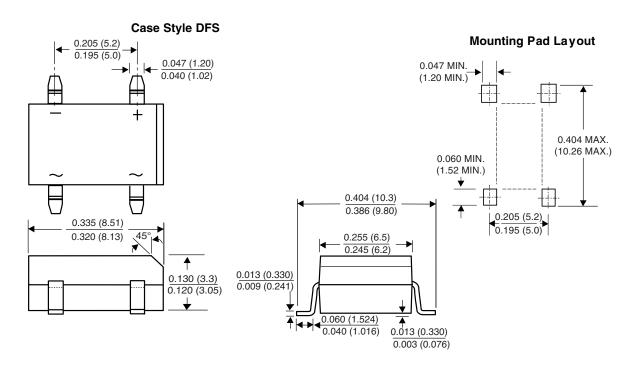


Fig. 5 - Typical Junction Capacitance Per Diode

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



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